## Supporting Information for

## Synthesis of Monolayer Gold Nanorings Sandwich Film and Its Higher Surface-Enhanced Raman Scattering Intensity

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## Figures, Equation and Simulation:



Figure S1. Representative SEM images of monolayer Au nanorings without (A) and with (B) Ag cover and their corresponding EDS data shown below.


Figure S2. SEM image of Au nanorings self-assembled in LB process using different concentration of MPTMS in the solution: $1 \mathrm{~mL} 0.01 \mathrm{mM}(\mathbf{A}), 1 \mathrm{~mL} 1 \mathrm{mM}(\mathbf{B}), 1 \mathrm{~mL} 10 \mathrm{mM}(\mathbf{C}),(\mathbf{D})$ is the low magnification of (B).


Figure S3. UV-vis-NIR spectrum of the Au nanorings dispersed in deionized water.

## Equation S1:

Definition: $\boldsymbol{\lambda}_{1}$, wavelength of incident light; $\boldsymbol{\lambda}_{2}$, wavelength of Raman scattering; $\boldsymbol{\Delta} \boldsymbol{v}$, Raman shift.

$$
\frac{1}{\lambda_{1}}-\frac{1}{\lambda_{2}}=\Delta v\left(1000 \sim 1573 \mathrm{~cm}^{-1}\right. \text {, see Figure S4) }
$$

$$
\begin{gathered}
\frac{1}{632.8 \times 10^{-7} \mathrm{~cm}}-\frac{1}{\lambda_{2}}=1000 \sim 1573 \mathrm{~cm}^{-1} \\
\frac{1}{\lambda_{2}}=14802 \sim 14229 \mathrm{~cm}^{-1} \\
\lambda_{2}=675 \sim 702 \mathrm{~nm}
\end{gathered}
$$



Figure S4 SERS intensities from blank Ag substrate (black), and from monolayer Au nanorings on Ag substrate (red).


Figure S5. Height profiles of different thickness of Ag cover films, (A) ~9 nm, (B) ~15 nm, and (C) ~30 nm on Si substrate.

## Simulation method:

In FDTD simulations, the radii of inner Pt wire and Pt@Au wire were set to 22 nm and 44 nm , respectively. These values were the same as the experimental ones. The EM field distribution at crosssection of sandwich-type films with different Ag cover thickness subjected to 633 nm laser irradiation is simulated. FDTD method is used to solve Maxwell's equations in nonmagnetic materials:

$$
\begin{align*}
& \frac{\partial \vec{D}}{\partial t}=\nabla \times \vec{H}  \tag{1}\\
& \vec{D}(\omega)=\varepsilon_{0} \varepsilon_{r} \vec{E}(\omega)  \tag{2}\\
& \frac{\partial \vec{H}}{\partial t}=-\frac{1}{\mu_{0}} \nabla \times \vec{E} \tag{3}
\end{align*}
$$

where $\mathrm{H}, \mathrm{E}$, and D are the magnetic, electric, and displacement fields, respectively. $\varepsilon$ and $\mu_{0}$ are the complex relative dielectric constant and magnetic permeability coefficient, respectively.

In three dimensions, Maxwell equations have six EM field components. With the assumption that the structure is infinite in the $z$ dimension and that the fields are independent of $z$, the Maxwell's equations are split into two independent groups of equations that can be solved in the $x-y$ plane only, which results in the transverse electric (TE) and transverse magnetic (TM) equations. Then, we can use the components of $\mathrm{E}_{x}, \mathrm{E}_{\mathrm{y}}$, and $\mathrm{H}_{z}$ to solve TE equations and those of $\mathrm{H}_{x}, \mathrm{H}_{y}$, and $\mathrm{E}_{z}$ to solve TM equations.

$$
\begin{gather*}
\frac{\partial E_{z}}{\partial y}-\frac{\partial E_{y}}{\partial z}=-\mu_{0} \frac{\partial H_{x}}{\partial t}  \tag{4}\\
\frac{\partial E_{x}}{\partial z}-\frac{\partial E_{z}}{\partial x}=-\mu_{0} \frac{\partial H_{y}}{\partial t}  \tag{5}\\
\frac{\partial E_{y}}{\partial x}-\frac{\partial E_{x}}{\partial y}=-\mu_{0} \frac{\partial H_{z}}{\partial t}  \tag{6}\\
\frac{\partial H_{z}}{\partial y}-\frac{\partial H_{y}}{\partial z}=\varepsilon \frac{\partial E_{x}}{\partial t}  \tag{7}\\
\frac{\partial H_{x}}{\partial z}-\frac{\partial H_{z}}{\partial x}=\varepsilon \frac{\partial E_{y}}{\partial t}  \tag{8}\\
\frac{\partial H_{y}}{\partial x}-\frac{\partial H_{x}}{\partial y}=\varepsilon \frac{\partial E_{z}}{\partial t} \tag{9}
\end{gather*}
$$

Considering that the function $f(x, y, z, t)$ denotes the electric or magnetic field in the coordinate system, it can be discretized via the central difference approximation in both space and time.

$$
\begin{align*}
& \left.\frac{\partial f(x, y, z, t)}{\partial x}\right|_{x=i \Delta x} \approx \frac{f^{n}(i+0.5, j, k)-f^{n}(i-0.5, j, k)}{\Delta x}  \tag{10}\\
& \left.\frac{\partial f(x, y, z, t)}{\partial y}\right|_{y=j \Delta y} \approx \frac{f^{n}(i, j+0.5, k)-f^{n}(i, j-0.5, k)}{\Delta y} \tag{11}
\end{align*}
$$

$$
\begin{align*}
& \left.\frac{\partial f(x, y, z, t)}{\partial z}\right|_{z=k \Delta z} \approx \frac{f^{n}(i, j, k+0.5)-f^{n}(i, j, k-0.5)}{\Delta z}  \tag{12}\\
& \left.\frac{\partial f(x, y, z, t)}{\partial t}\right|_{t=n \Delta t} \approx \frac{f^{n+0.5}(i, j, k)-f^{n-0.5}(i, j, k)}{\Delta t} \tag{13}
\end{align*}
$$

